NSN 5961-00-501-1006

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-501-1006 **Inclosure Material:** Ceramic and glass **Overall Length:** 0.080 inches **Terminal Length:** 0.157 inches **Overall Diameter:** 0.210 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 3.5 gate to source cutoff voltage and 35.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 15.00 milliamperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 175.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 13499-352-0756 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No